

40V N-Channel Enhancement Mode MOSFET

Voltage

40 V

Current

70 A

Features

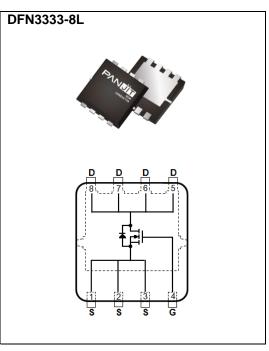
- R_{DS(ON)}, V_{GS}@10V, I_D@20A<5.5mΩ
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_{D}@10A<7.5m\Omega$
- Advanced Trench Process Technology
- High density cell design for ultralow on-resistance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: DFN3333-8L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.03 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	40	V	
Gate-Source Voltage		V _{GS}	<u>+</u> 20] V	
Continuous Drain Current	Tc=25°C	l _D	70	A	
	Tc=100°C		45		
Pulsed Drain Current(Note 1)	Tc=25°C	I _{DM}	240		
Power Dissipation	Tc=25°C	Po	50	10/	
	Tc=100°C		44.3	W	
Continuous Drain Current	T _A =25°C	l _D	14	А	
	T _A =70°C		11		
Power Dissipation	T _A =25°C	-	2.0	W	
Power Dissipation	T _A =70°C	Po	1.3		
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C	
Typical Thermal Resistance ^(Note 4,5)	Junction to Case	R ₀ JC	2.5	°C/W	
	Junction to Ambient	R _{0JA}	62.5		

• Limited only By Maximum Junction Temperature



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	40	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} , I _D =250uA	1.0	1.75	2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =20A	-	4.2	5.5	mΩ
		V _{GS} =4.5V, I _D =10A	-	5.3	7.5	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =40V, V _{GS} =0V	-	-	1.0	uA
Gate-Source Leakage Current	Igss	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic ^(Note 6)						
Total Gate Charge	Qg	V _{DS} =32V, I _D =10A, V _{GS} =4.5V ^(Note 2,3)	-	25	-	nC
Gate-Source Charge	Qgs		-	7	-	
Gate-Drain Charge	Q_{gd}		-	10	-	
Input Capacitance	Ciss	V _{DS} =25V, V _{GS} =0V,	-	1258	-	pF
Output Capacitance	Coss		-	134	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	88	-	
Turn-On Delay Time	td _(on)		-	18	-	
Turn-On Rise Time	t _r	$V_{DS}=20V, I_{D}=1A,$ $V_{GS}=10V, R_{G}=3.3\Omega$ (Note 2,3)	-	13	-	ns
Turn-Off Delay Time	td _(off)		-	109	-	
Turn-Off Fall Time	t _f	(100 2,0)	-	73	-	
Drain-Source Diode						
Maximum Continuous Drain-Source			-	-	70	А
Diode Forward Current	I _S					
Diode Forward Voltage	V _{SD}	I _S =1A, V _{GS} =0V	-	0.7	1	V

NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.

February 18,2023 PJQ4444P-REV.03 Page 2



TYPICAL CHARACTERISTIC CURVES

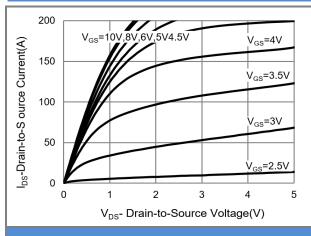


Fig.1 On-Region Characteristics

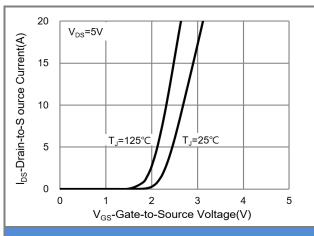


Fig.2 Transfer Characteristics

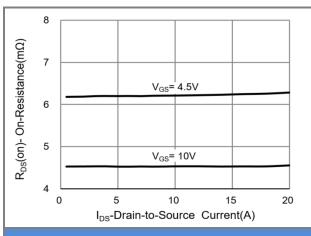


Fig.3 On-Resistance vs. Drain Current

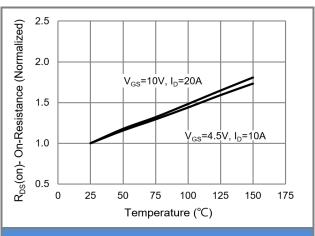


Fig.4 On-Resistance vs. Junction temperature

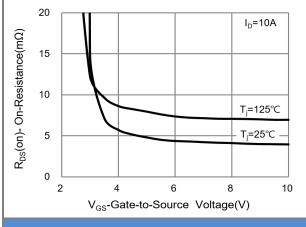


Fig.5 On-Resistance Variation with V_{GS}

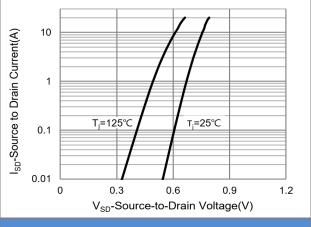


Fig.6 Source-Drain Diode Forward Voltage



TYPICAL CHARACTERISTIC CURVES

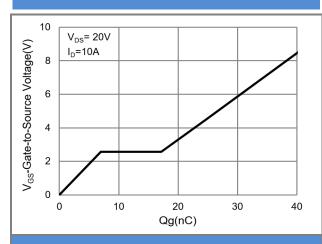


Fig.7 Gate-Charge Characteristics

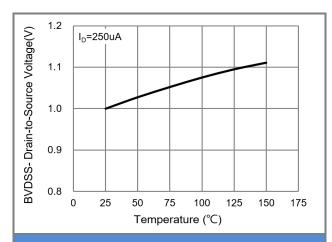


Fig.8 Breakdown Voltage Variation vs. Temperature

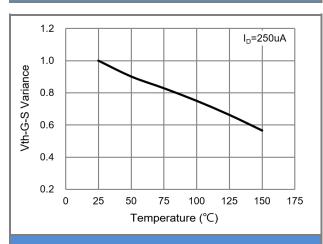


Fig.9 Threshold Voltage Variation with Temperature

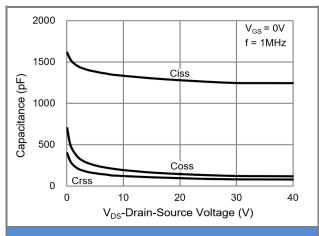
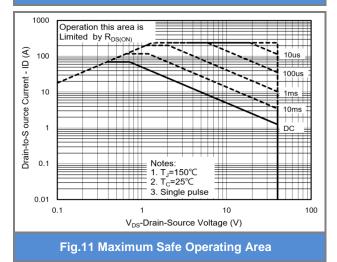


Fig.10 Capacitance vs. Drain-Source Voltage



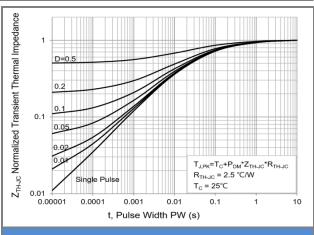


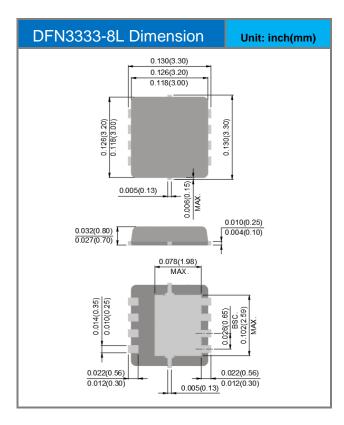
Fig.12 Normalized Transient Thermal Impedance

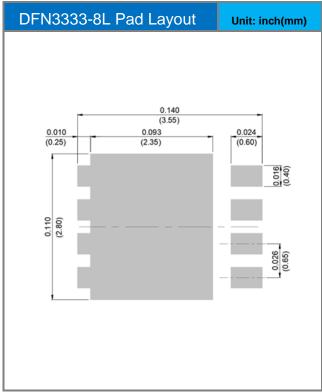


Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ4444P_R2_00001	DFN3333-8L	5K pcs / 13" reel	4444	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout







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February 18,2023 PJQ4444P-REV.03 Page 6